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## Inclosure Material:

Metal
Overall Length:
0.460 inches

Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud

## Features Provided:

Hermetically sealed case

## Overall Width Across Flats:

0.687 inches

Thread Size:
0.250 inches

Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:
Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current

## Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction

## Special Features:

Junction pattern arrangement: npn
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:

## Demilitarization:

No
Fiig:
A110a0

